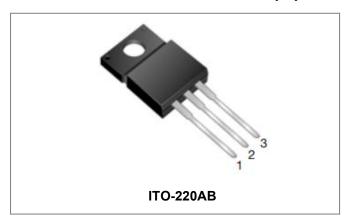






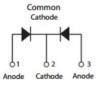
STF30200C(R) SCHOTTKY RECTIFIER

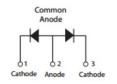


Features

- 175 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram





STF30200C

STF30200CR

Applications

- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	Tc=84°C, In DC	15(Per Leg) 30(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	200	А

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	DC operation	5.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

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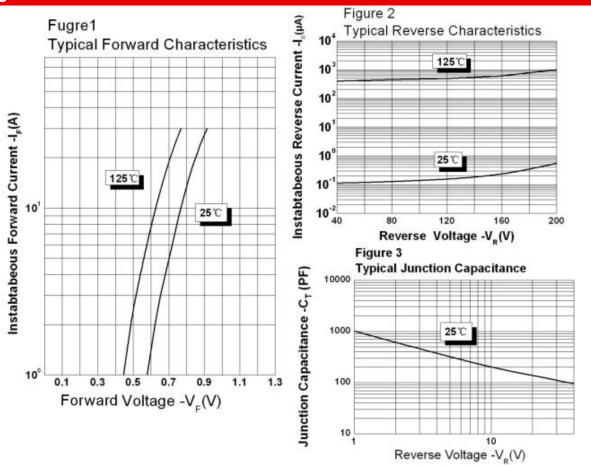


Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*		@ 5A, Pulse, T _J = 25°C	0.70	-	
	V_{F1}	@ 7.5A, Pulse, T _J = 25°C	0.78	-	V
		@ 15A, Pulse, T _J = 25℃	0.81	1.10	
		@ 5A, Pulse, T _J = 125℃	0.56	-	
	V_{F2}	@ 7.5A, Pulse, T _J =125℃	0.61	-	V
		@ 15A, Pulse, T _J = 125℃	0.68	0.72	
Reverse Current(Per Leg)*	I_{R1}	@V _R = rated V _R , T _J = 25 ℃	0.0005	0.16	mA
	I_{R2}	@V _R = rated V _R , T _J = 125℃	1	12	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	300	-	рF
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, T _A = 25 °C)		Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	
	V_{ISO}	Clip mounting, the epoxy body is inside the heatsink.	-	3500	V
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

^{*} Pulse width < 300 µs, duty cycle < 2%

Ratings and Characteristics Curves



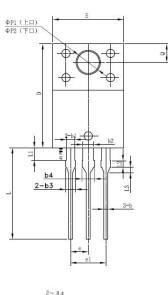
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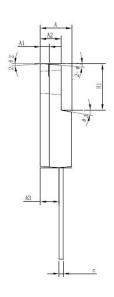






Mechanical Dimensions ITO-220AB

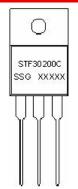


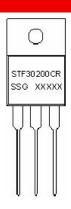




SYMBOL	Millimeters			
STWIDOL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
<u>L1</u>	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦΡ1(├ □)	3.30	3.50	3.70	
ΦP2 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

Marking Diagram





Where XXXXX is YYWWL

 ST
 = Device Type

 F
 = Package type

 30
 = Forward Current (30A)

 200
 = Reverse Voltage (200V)

 C(R)
 = Configuration

 SSG
 = SSG

 YY
 = Year

YY = Year WW = Week L = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Tube Specification



Ordering Information

Device	Package	Shipping
STF30200C(R)	ITO-220AB (Pb-Free)	50 pcs/ tube

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